## Computational Chemistry and Materials Modeling Lecture 3 Density Functional Theory

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### Hartree-Fock Theory

### The Hartree-Fock approximation

### Slater determinant fulfills the Pauli principle

$$\Psi(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N) = \frac{1}{N!} \begin{vmatrix} \psi_1(\mathbf{r}_1) & \psi_2(\mathbf{r}_1) & \dots & \psi_N(\mathbf{r}_1) \\ \psi_1(\mathbf{r}_2) & \psi_2(\mathbf{r}_2) & \dots & \psi_N(\mathbf{r}_2) \\ \dots & & \\ \psi_1(\mathbf{r}_N) & \psi_2(\mathbf{r}_N) & \dots & \psi_N(\mathbf{r}_N) \end{vmatrix}$$

### Hartree-Fock equation

$$\begin{bmatrix} -\frac{\hbar^2}{2m} \nabla_i^2 + V_{ext}(\mathbf{r}) \end{bmatrix} \psi_i(\mathbf{r}) + e^2 \sum_j \int \frac{\psi_j^*(\mathbf{r}')\psi_j(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' \psi_i(\mathbf{r}) \\ - e^2 \sum_j \int \frac{\psi_j^*(\mathbf{r}')\psi_i(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' \psi_j(\mathbf{r}) = E_i \psi_i(\mathbf{r})$$

## Hartree-Fock Theory

### **Configuration interaction (CI)**

Linear combination of Slater determinants Correlation effects taken into account Leads to the energetically preferred solution Leads generally to the exacte solution Only for small systems doable Van Vleck catastrophy



 $\Phi(\mathbf{r}_1, \mathbf{r}_2, \dots \mathbf{r}_N)$ 

### The many-body wavefunction of 1000 electrons cannot be stored in the whole universe

Van Vleck catastrophy (1936)

W. Kohn, Rev. Mod. Phys. 11, 1253 (1999).

C. Some meta-physical-chemical considerations

The following remarks are related to a very old paper by one of my teachers, J. H. Van Vleck (1936), in which he discusses a problem with many-body wave functions, later referred to as the Van Vleck catastrophy.

I begin with a provocative statement. In general the many-electron wave function  $\Psi(r_1, \ldots, r_N)$  for a system of N electrons is not a legitimate scientific concept, when  $N \ge N_0$ , where  $N_0 \approx 10^3$ .

A simpler example

Ne atom

 $\Phi(\mathbf{r}_1, \mathbf{r}_2, \mathbf{r}_3, \mathbf{r}_4, \mathbf{r}_5, \mathbf{r}_6, \mathbf{r}_7, \mathbf{r}_8, \mathbf{r}_9, \mathbf{r}_{10})$ 

- 10 electrons
- 30 coordinates
- 10 entries for each coordinate 10<sup>30</sup> entries
- 10<sup>30</sup> bytes 1 byte per entry 5 x 10<sup>9</sup> bytes per DVD

2 x 10<sup>20</sup> DVDs

16 GB per smartphone 7 x 10<sup>9</sup> people on earth smartphones / person

~10<sup>20</sup> smartphones 1.5 x 10<sup>10</sup>

Storing is not an option (maybe calculating on demand is)

## Density-functional theory

In principle, we need to know the many-electron wave function

$$\Phi(\{\mathbf{r}_i\}) = \Phi(\mathbf{r}_1, \mathbf{r}_2, \dots \mathbf{r}_N)$$

depending on the coordinates of all electrons

According to Hohenberg and Kohn, only the electron density is required

 $n(\mathbf{r})$ 

depending on three coordinates: x, y, z

### Questions

- Do we really need the many-body wave function?
- Can we compute the electron distribution without explicitly knowing the WF?

$$n(\mathbf{r}) = \left\langle \Phi(\{\mathbf{r}_i\}) \left| \sum_{i}^{N} \delta(\mathbf{r} - \mathbf{r}_i) \right| \Phi(\{\mathbf{r}_i\}) \right\rangle$$

$$n(\mathbf{r}) = N \int \Phi^*(\mathbf{r}, \mathbf{r}_2, \dots, \mathbf{r}_N) \Phi(\mathbf{r}, \mathbf{r}_2, \dots, \mathbf{r}_N) d^3r_2 \dots d^3r_N$$

## Density-functional theory

### Literature

P. Hohenberg, W. Kohn, Phys. Rev. 136, B864 (1964)

W. Kohn, L. Sham, Phys. Rev. A 140,1133 (1965)

R.M. Dreizler, E.K.U. Gross, Density Functional Theory (Spinger, 1990)

R .G. Parr, W. Yang, Density-Functional Theory of Atoms and Molecules (Oxford University Press 1994)

R.O. Jones and O. Gunnarsson, Rev. Mod. Phys. 61, 689 (1989)

K. Burke, ABC of DFT: http://dft.uci.edu/sites/default/files/g1.pdf

### Hohenberg-Kohn theorem

P. Hohenberg, W. Kohn, Phys. Rev. 136, B864 (1964)

□ I: The total energy of an interacting system of electrons is a unique functional of the density

$$E = F[n(\mathbf{r})] + \int V_{e\times t}(\mathbf{r})n(\mathbf{r})d\mathbf{r}$$

The functional *F* does not depend on the external potential!

II: The energy takes its minimum at the groundstate density

I: Uniqueness: We need to show that there is only one potential that leads to a certain density

### I: Uniqueness: We need to show that there is only one potential that leads to a certain density

**Given**  $H^e$ ,  $V_{ext}$ ,  $E = \langle \Phi(\{\mathbf{r}_i\}) | H^e | \Phi(\{\mathbf{r}_i\}) \rangle$ ,  $n(\mathbf{r})$ 

Assume there is another potential such that we have

$$\tilde{H}^{e}_{,,} \tilde{V}_{ext}_{,,} \tilde{E} = \left\langle \tilde{\Phi}(\{\mathbf{r}_{i}\}) \left| \tilde{H}^{e} \right| \tilde{\Phi}(\{\mathbf{r}_{i}\}) \right\rangle \tilde{n}(\mathbf{r}) = n(\mathbf{r})$$
$$\tilde{E} = \left\langle \tilde{\Phi} \left| \tilde{H}^{e} \right| \tilde{\Phi} \right\rangle < \left\langle \Phi \left| \tilde{H}^{e} \right| \Phi \right\rangle = \left\langle \Phi \left| H^{e} - V_{ext} + \tilde{V}_{ext} \right| \Phi \right\rangle$$

+  $\tilde{E} < E + \left( \Phi \tilde{V}_{ext} - V_{ext} \Phi \right)$ +  $E < \tilde{E} + \left( \Phi V_{ext} - \tilde{V}_{ext} \Phi \right)$ impossible!

Two potentials cannot lead to the same density

Proof of HK theorem

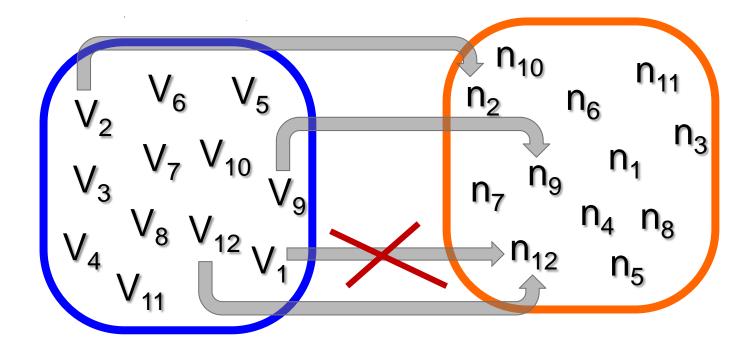
+ 
$$\tilde{E} < E + \left\langle \Phi \left| \tilde{V}_{ext} - V_{ext} \right| \Phi \right\rangle = E + \int d\mathbf{r} \left( \tilde{V}_{ext} - V_{ext} \right) n(\mathbf{r})$$
+ 
$$E < \tilde{E} + \left\langle \tilde{\Phi} \left| V_{ext} - \tilde{V}_{ext} \right| \tilde{\Phi} \right\rangle = \tilde{E} + \int d\mathbf{r} \left( V_{ext} - \tilde{V}_{ext} \right) \tilde{n}(\mathbf{r})$$

$$\tilde{n}(\mathbf{r}) = n(\mathbf{r})$$

$$\tilde{E} + \int d\mathbf{r} \left( V_{ext} - \tilde{V}_{ext} \right) n(\mathbf{r})$$

 $\tilde{E} + E < E + \tilde{E} \implies \tilde{n}(\mathbf{r}) \neq n(\mathbf{r})$ impossible!

### There is a one-to-one correspondence between density and potential



Part II: The ground state energy can be obtained variationally: The density that minimizes the total energy is the ground-state density

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 $n(\boldsymbol{r}) \to \hat{V}_{ext} \to \hat{H}^e = \hat{F} + \hat{V}_{ext} \to \Phi(\{\boldsymbol{r}_i\}) \Rightarrow \left\langle \Phi \left| \hat{F} \right| \Phi \right\rangle \equiv F[n(\boldsymbol{r})]$ 

The total energy is a functional of the density:

$$E[n(\mathbf{r})] = F[n(\mathbf{r})] + \int V_{ext}(\mathbf{r})n(\mathbf{r})d\mathbf{r}$$

A density that is a ground state of some external potential is called V-representable

$$E[n'(\mathbf{r})] = F[n'(\mathbf{r})] + \int V_{ext}(\mathbf{r})n'(\mathbf{r})d\mathbf{r} = \langle \Phi' | \hat{F} | \Phi' \rangle + \langle \Phi' | \hat{V}_{ext} | \Phi' \rangle$$

Part II: The ground state energy can be obtained variationally: The density that minimizes the total energy is the ground-state density

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For a ground state density:

$$E[n(\mathbf{r})] = F[n(\mathbf{r})] + \int V_{ext}(\mathbf{r})n(\mathbf{r})d\mathbf{r} = \langle \Phi | \hat{F} | \Phi \rangle + \langle \Phi | \hat{V}_{ext} | \Phi \rangle$$

From variational principle:

 $\left\langle \Phi' \left| \hat{F} \right| \Phi' \right\rangle + \left\langle \Phi' \left| \hat{V}_{ext} \right| \Phi' \right\rangle > \left\langle \Phi \left| \hat{F} \right| \Phi \right\rangle + \left\langle \Phi \left| \hat{V}_{ext} \right| \right] \Phi \right\rangle$ 

 $E[n'(\boldsymbol{r})] > E[n(\boldsymbol{r})]$ 

- □ The HK theorem is exact for the ground state
- It is beautiful as we only need to know one = THE functional to describe any system Atoms, molecules, solids, surfaces, nano-structures
- The only problem is that we don't know this functional Thus DFT is not practical so far

Kohn and Sham set the stage for the practicality of DFT W. Kohn, L. Sham, Phys. Rev. A 140,1133 (1965)

# One can divide the energy functional into three contributions:

$$F[n(\mathbf{r})] = T[n(\mathbf{r})] + \frac{1}{2} \iint \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}' + E_{xc}[n(\mathbf{r})]$$

# We still don't have a good expression for the kinetic energy

This problem is, however, diminished by introducing single-particle functions which give the exact density:

$$n(\mathbf{r}) = \sum_{i}^{N} |u_i(\mathbf{r})|^2$$

We will now carry out the variation with respect to the density through a variation with respect to the single-particle functions.

Kohn-Sham equations

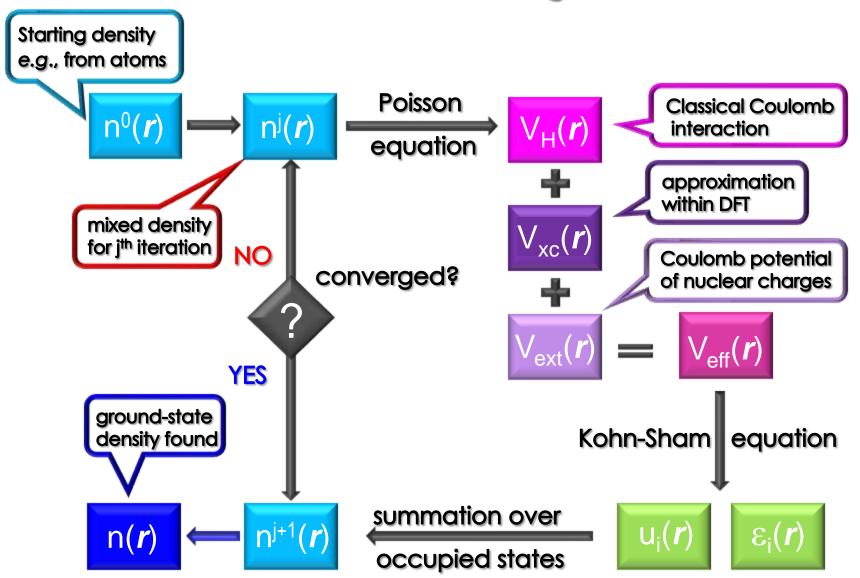
$$\begin{cases} -\frac{1}{2}\nabla^2 + V_{ext}(\mathbf{r}) + \int d\mathbf{r}' \underbrace{\sum_j u_j^*(\mathbf{r}') u_j(\mathbf{r}')}_{j} \frac{1}{|\mathbf{r} - \mathbf{r}'|} + V_{xc}(\mathbf{r}) - \epsilon_i \\ V \\ \left\{ -\frac{1}{2}\nabla^2 + V_{ext}(\mathbf{r}) + \int d\mathbf{r}' n(\mathbf{r}') \frac{1}{|\mathbf{r} - \mathbf{r}'|} + V_{xc}(\mathbf{r}) - \epsilon_i \right\} u_i(\mathbf{r}) = 0 \end{cases}$$

$$\left\{-\frac{1}{2}\nabla^2 + V_{ext}(\mathbf{r}) + \int d\mathbf{r}' n(\mathbf{r}') \frac{1}{|\mathbf{r} - \mathbf{r}'|} + V_{xc}[n(\mathbf{r})] - \epsilon_i \right\} u_i(\mathbf{r}) = 0$$

approximation needed – only approximation! contains xc effects and corrections to kinetic energy

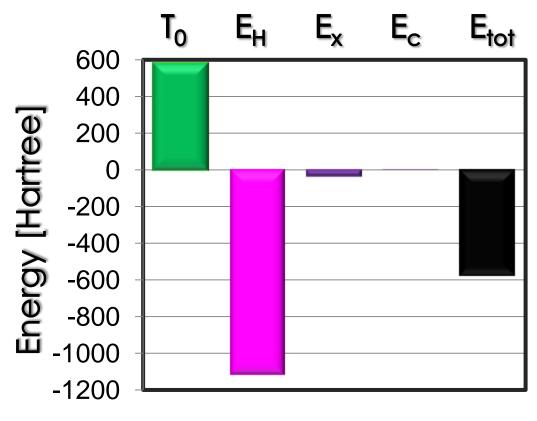
- Caution: The Kohn-Sham eigenvalues were derived as Lagrange parameters of the variation procedure and cannot a priori be interpreted as single-particle energies.
- The Kohn-Sham orbitals are auxiliary quantities which produce the exact density.
- □ The only approximation required for the ground state is V<sub>xc</sub>.
- The potential is a functional of the density which is obtained from the KS orbitals; these, in turn, give the density. Thus the KS equation must be solved self-consistently.

## Self-consistent field cycle



## Energy contributions

**Example: Si** 



### Local-density approximation (LDA)

xc effects taken from homogenous electron gas

$$E_{xc}^{LDA} = \int d\mathbf{r} \ n(\mathbf{r}) \epsilon_{xc}^{unif}[n(\mathbf{r})]$$

Exchange is known analytically:

$$\epsilon_{x}(r_{s}) = -\frac{3}{2\pi} \left(\frac{9\pi}{4}\right)^{\frac{1}{3}} \frac{1}{r_{s}} \qquad r_{s} = \left[\frac{3}{4\pi n(\mathbf{r})}\right]^{\frac{1}{3}}$$

Correlation: high- and low-density limits are known analytically:

$$\epsilon_c = A \ln(r_s) + B + r_s(C \ln(r_s) + D)$$
 - high density

### Local-density approximation (LDA)

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## Correlation: high- and low-density limits are known analytically:

$$\epsilon_c = -\frac{0.438}{r_s} + \frac{1.33}{r_s^{3/2}} - \frac{1.47}{r_s^2}$$

- low-density (electrons form a BCC lattice called Wigner crystal)

### Local-density approximation (LDA)

Neither the high nor the low-density limits are useful for ordinary matter

For the intermediate densities, one can parametrize an exact numerical solution (e.g., obtained with quantum Monte Carlo)

e.g., Hedin & Lundquist, 1971

$$\epsilon_c[n(\mathbf{r})] = 0.045 \left[ \left( 1 + x^3 \right) \ln \left( 1 + \frac{1}{x} \right) + \frac{x}{2} - x^2 - \frac{1}{3} \right] \qquad x = \frac{r_s}{21}$$

□ Many features of the exact  $E_{XC}[n]$  are known → constraints on the approximate functional

Limiting behavior for  $n(r) \rightarrow \infty$  and  $n(r) \rightarrow 0$ 

Lieb-Oxford bound:

$$\left| \Phi \left| \frac{1}{2} \sum_{i \neq j} \frac{1}{r_{ij}} \right| \Phi \right| - \frac{1}{2} \int \frac{n_{\Phi}(\boldsymbol{r}) n_{\Phi}(\boldsymbol{r}')}{|\boldsymbol{r} - \boldsymbol{r}'|} d\boldsymbol{r} d\boldsymbol{r}' \ge 1.68 \int n_{\Phi}(\boldsymbol{r})^{\frac{4}{3}} d\boldsymbol{r}$$

LDA satisfies these constraints

□ Many features of the exact  $E_{XC}[n]$  are known  $\rightarrow$  constraints on the approximate functional

Express  $E_{xc}[n]$  through exchange-correlation hole (change due to XC of probability to find an electron at rwhen another electron is at r', can be measured!):

□ Many features of the exact  $E_{XC}[n]$  are known  $\rightarrow$  constraints on the approximate functional

Express  $E_{XC}[n]$  through exchange-correlation hole (change due to XC of probability to find an electron at rwhen another electron is at r'):

$$E_{XC}[n] = \frac{1}{2} \int d\mathbf{r} \, n(\mathbf{r}) \int d\mathbf{u} \, \frac{h_{XC}(\mathbf{r}, \mathbf{r} + \mathbf{u})}{|\mathbf{u}|}$$
  
Sum rules:

 $\int d\boldsymbol{u} h_X(\boldsymbol{r},\boldsymbol{r}+\boldsymbol{u}) = -1, \qquad \int d\boldsymbol{u} h_C(\boldsymbol{r},\boldsymbol{r}+\boldsymbol{u}) = 0$ 

**Local conditions:**  $h_X(\mathbf{r},\mathbf{r}+\mathbf{u}) \le 0 \ \forall \mathbf{r},\mathbf{u}, \qquad h_X(\mathbf{r},\mathbf{r}) = -\frac{n(\mathbf{r})}{2}$ (no spin)

#### LDA satisfies all these constraints!

What about spin?

### Local spin density approximation (LSDA)

The total energy is a unique functional of the density, but the wave function is not - any normalized linear combination of wave functions with the same energy gives the same density

If  $\hat{H}$  does not depend on spin, there are 2S + 1 wave functions with the same energy and the same total spin S

Constrain number of spin-up and spin-down electrons separately  $\rightarrow E[n_{\alpha}, n_{\beta}] = \langle \Phi | \hat{H} | \Phi \rangle_{\Phi \rightarrow n_{\alpha}, n_{\beta}}$ Generalizations of the HK theorem to  $E[n_{\alpha}, n_{\beta}]$  exist

Example: Cu

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PHYSICAL REVIEW LETTERS

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#### Absolute Band Mapping by Combined Angle-Dependent Very-Low-Energy Electron Diffraction and Photoemission: Application to Cu

V. N. Strocov,<sup>1,2,\*</sup> R. Claessen,<sup>1</sup> G. Nicolay,<sup>1</sup> S. Hüfner,<sup>1</sup> A. Kimura,<sup>3</sup> A. Harasawa,<sup>3</sup> S. Shin,<sup>3</sup> A. Kakizaki,<sup>4</sup> P. O. Nilsson,<sup>2</sup> H. I. Starnberg,<sup>2</sup> and P. Blaha<sup>5</sup>

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(Received 18 August 1998)

We present an experimental method to determine the electronic  $E(\mathbf{k})$  band structure in crystalline solids absolutely, i.e., with complete control of the three-dimensional wave vector  $\mathbf{k}$ . Angle-dependent very-low-energy electron diffraction is first applied to determine the unoccupied states whose  $\mathbf{k}$  is located on a high-symmetry line parallel to the surface. Photoemission via these states, employing the constant-final-state mode, is then utilized to map the valence bands along this line. We demonstrate the method by application to Cu, and find significant deviation from free-electron-like behavior in the unoccupied states, and from density-functional theory in the occupied states. [S0031-9007(98)07792-8]



PHYSICAL REVIEW B, VOLUME 63, 205108

#### Three-dimensional band mapping by angle-dependent very-low-energy electron diffraction and photoemission: Methodology and application to Cu

V. N. Strocov\* and R. Claessen Experimentalphysik II, Universität Augsburg, D-86135 Augsburg, Germany

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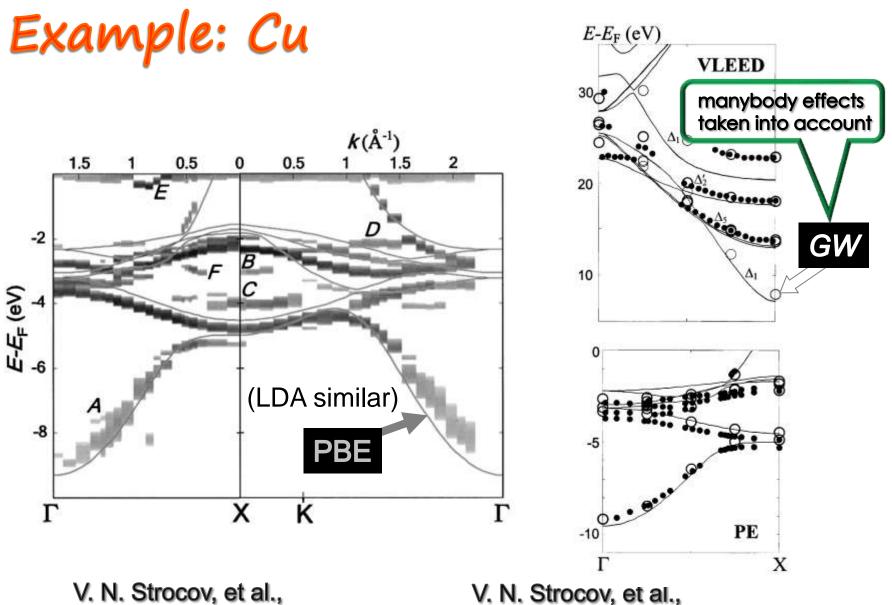
A. Kimura, A. Harasawa, and S. Shin Institute for Solid State Physics, University of Tokyo, Roppongi, Minato-ku, Tokyo 106-8666, Japan

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P. Blaha

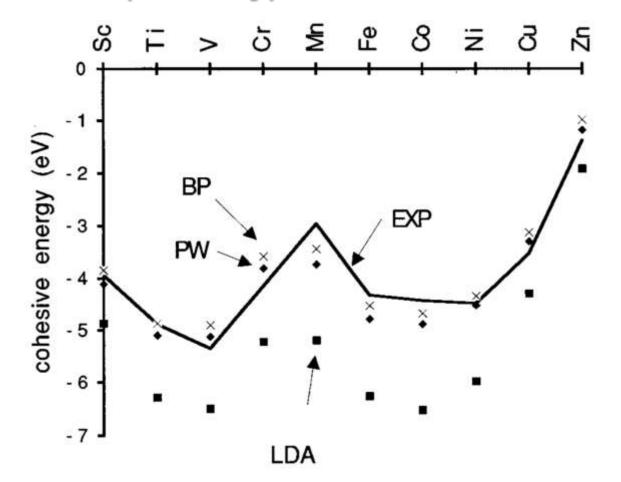
Institut für Physikalische und Theoretische Chemie, Technische Universität Wien, A-1060 Wien, Austria (Received 17 November 2000; revised manuscript received 2 February 2001; published 27 April 2001)



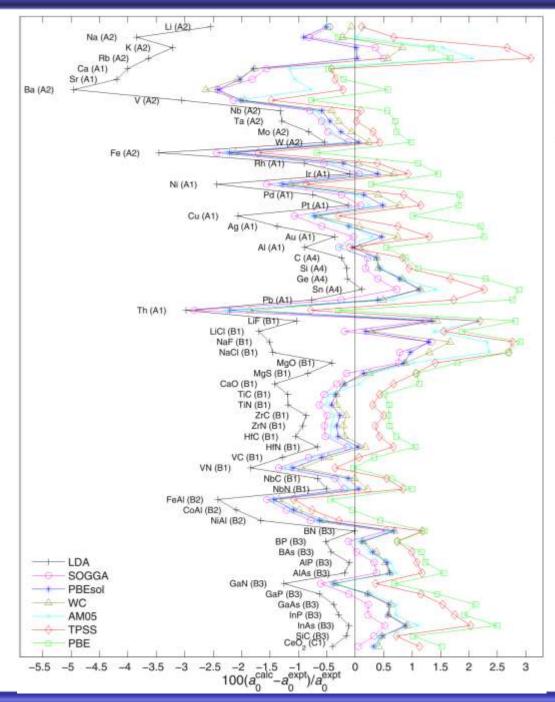
Phys. Rev. B 63, 205108 (2001).

V. N. Strocov, et al., Surface Rev. and Lett. 9, 1281 (2002).

How well (or badly) does LDA work?



Philipsen and Baerends, Phys. Rev. B, 54, p. 5326 (1996)



Equilibrium lattice constant compared to experiment

P. Haas, F. Tran, and P. Blaha, Phys. Rev. B 79, 085104 (2009)

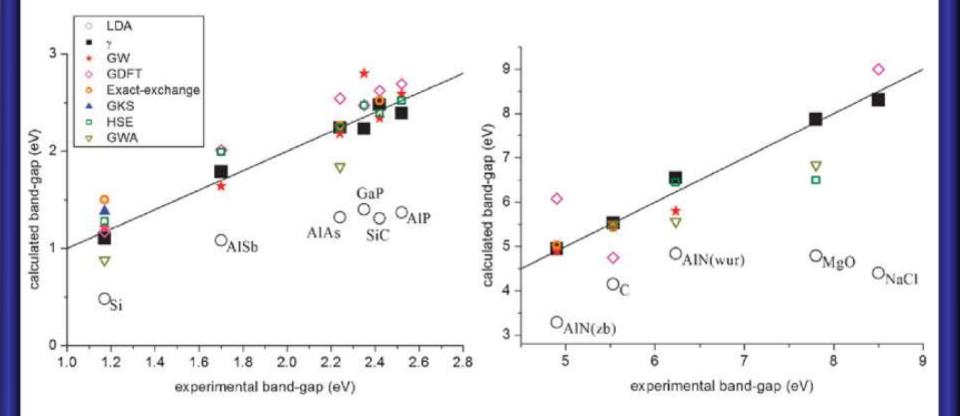
#### How well (or badly) does LDA work?

For total energies,  $E_X$  is underestimated by about 10%,  $E_C$  is overestimated by about 200%, so  $E_{XC}$  is good to about 7% (mysterious cancellation of errors).

For bond dissociation energies, LDA overbinds by about 1 eV/bond (30 kcal/mol), so no good for thermochemistry.

Typical bond lengths are underestimated by 1% (unless involving an H atom), so excellent geometries and vibrations. So still used for structure.

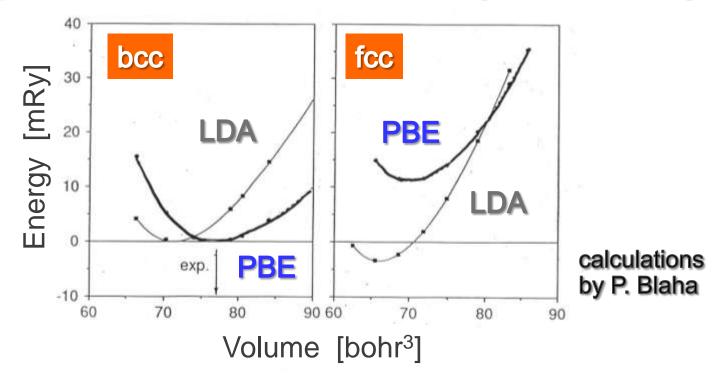
#### How well (or badly) does LDA work?



Philipsen and Baerends, Phys. Rev. B, 54, p. 5326 (1996)

### Example: Fe

#### It took until 1996 that the proper crystallographic phase of Fe could be correctly obtained by DFT



J. Perdew, K. Burke, and M. Ernzerhof, Phys. Rev. Lett. 77, 3865 (1996). More than 137000 citations

□ Generalized gradient approximation (GGA) Take into account local variations of the density:

 $E_{XC}^{GGA} = \int d\boldsymbol{r} \, n(\boldsymbol{r}) (\epsilon_X^{GGA}[n, |\nabla n|] + \epsilon_C^{GGA}[n, |\nabla n|])$ 

Gradient expansion approximation: expand  $E_{XC}$  for slowly varying electron gas in terms of  $\nabla n$  -- slow convergence

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Gradient expansion approximation: expand  $E_{XC}$  for slowly varying electron gas in terms of  $\nabla n$  — slow convergence

 $\epsilon_X^{GGA} = \epsilon_X^{HES}[n]F_X[n, \nabla n]$  (enhancement factor)

**PBE:** 
$$F_X = 1 + \kappa - \frac{\kappa}{1 + \mu s^2 / \kappa}, \quad s = \frac{|\nabla n(\boldsymbol{r})|}{2\kappa n(\boldsymbol{r})}$$
  
 $\epsilon_C^{GGA} = \epsilon_C^{LDA} + \frac{\beta^2}{2\alpha} \ln\left(1 + \frac{2\alpha}{\beta} \frac{s^2 + As^4}{1 + As^2 + A^2s^4}\right)$ 

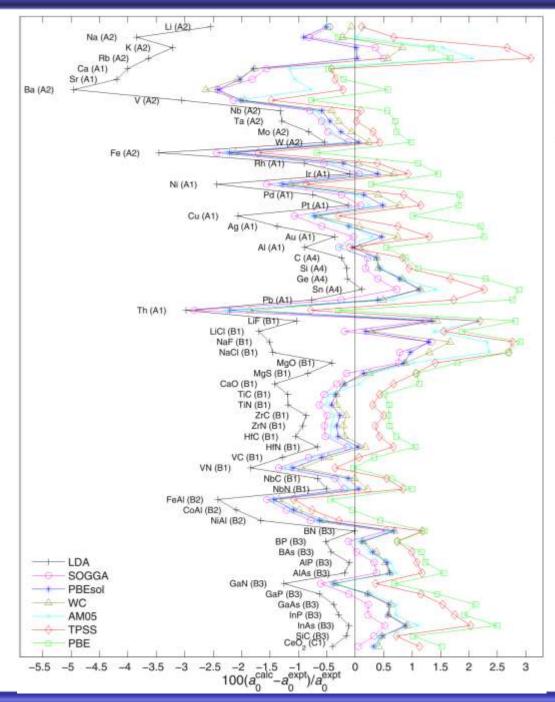
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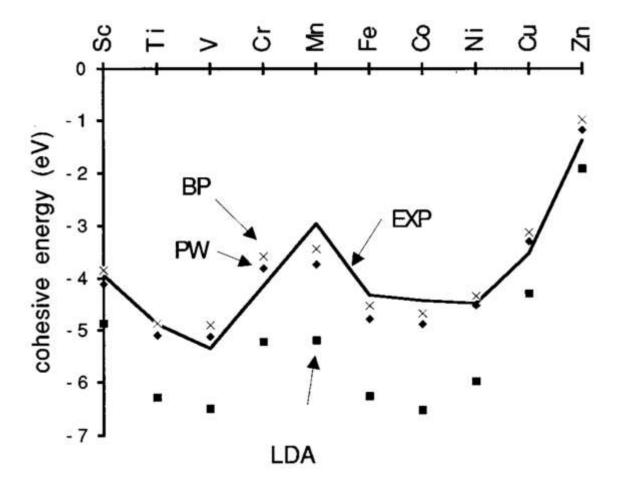
The parameters are chosen to satisfy the constraints (PBE: exchange hole sum rule and local, and Lieb-Oxford bound)



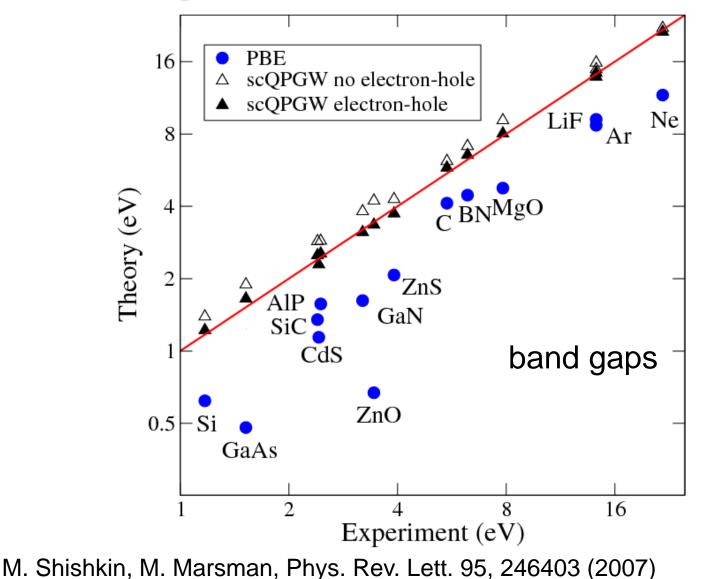
Equilibrium lattice constant compared to experiment

P. Haas, F. Tran, and P. Blaha, Phys. Rev. B 79, 085104 (2009)

Performance of GGAs



Philipsen and Baerends, Phys. Rev. B, 54, p. 5326 (1996)



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Meta-GGAs

$$E_{XC}^{GGA} = \int d\mathbf{r} \, n(\mathbf{r}) \epsilon_{XC}^{MGGA}(n, \nabla n, \tau)$$

with kinetic energy density  $\tau(\mathbf{r}) = \sum_{i}^{occup} \frac{1}{2} |\nabla \psi_i(\mathbf{r})|^2$ 

Although  $\tau$  is a non-local functional of n, it is available in standard calculations

For a 1-electron system,  $\tau$  is known exactly (Weizsäcker):

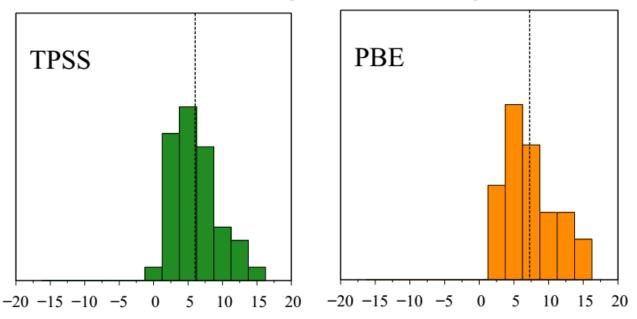
$$\tau^W = \frac{|\nabla n|^2}{8n}$$

Gradient expansion motivates use of  $\tau$ Functional is constructed similar to GGAs

Meta-GGAs

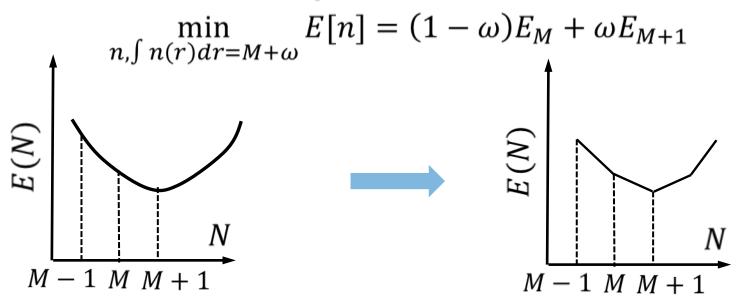
$$E_{XC}^{GGA} = \int d\boldsymbol{r} \, n(\boldsymbol{r}) \epsilon_{XC}^{MGGA}(n, \nabla n, \tau)$$

Histogram of lattice constatnt errors for a set of semiconductors (units: 0.01 A)



Lucero, Henderson, and Scuseria, J. Phys.: Cond. Matter 24, 145504 (2012) 47

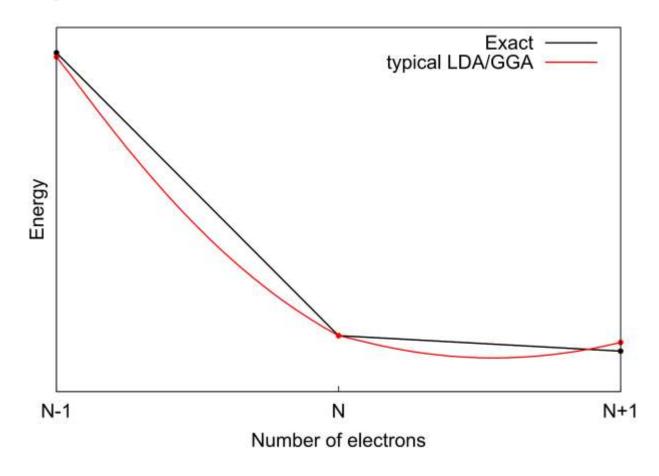
Fractional occupations



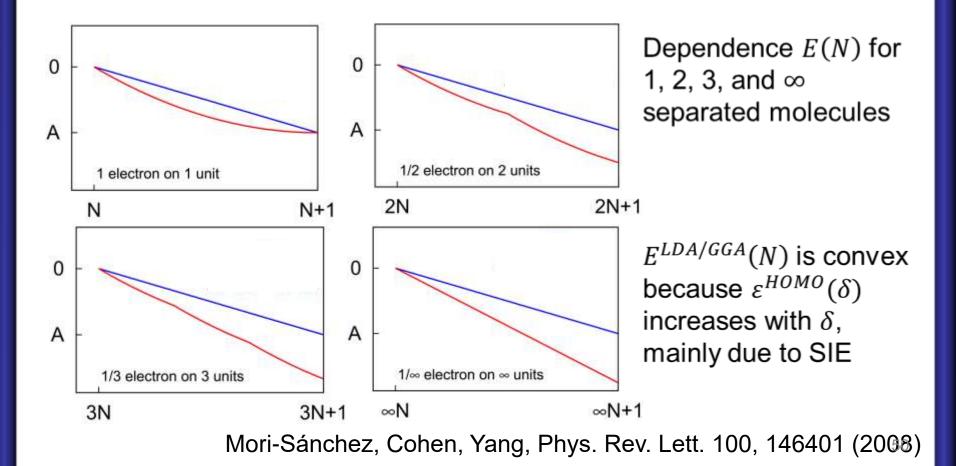
The exact energy changes piece-wise linear with N

Perdew et al., Phys. Rev. Lett. 49, 1691 (1982);

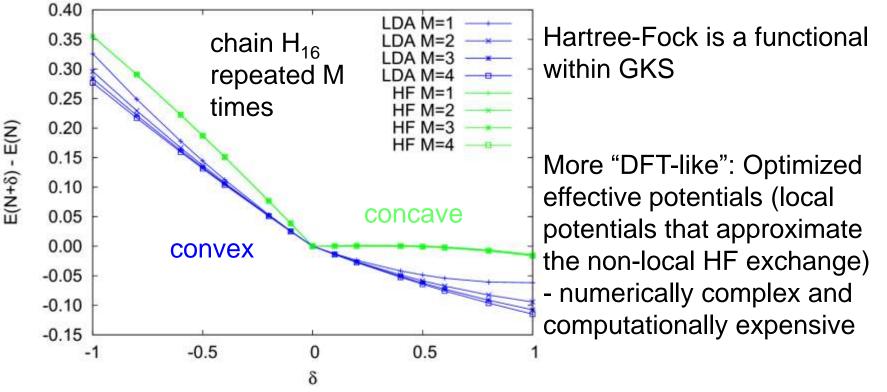
### Dependence of approximate DFT on the occupation



Connection between the self-interaction error (SIE) and the artificial delocalization

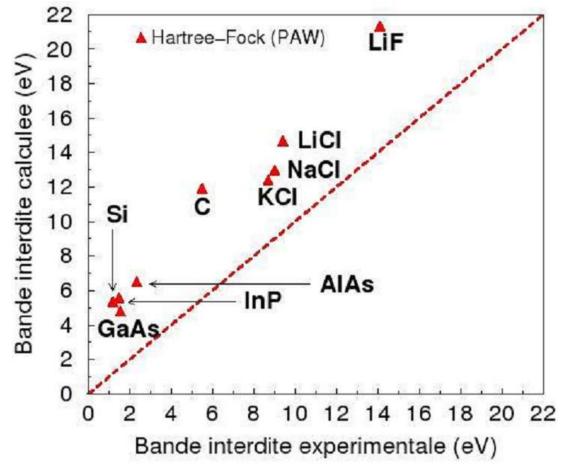


#### **Generalized Kohn-Sham (GKS):** $E = E[\{\psi\}]$



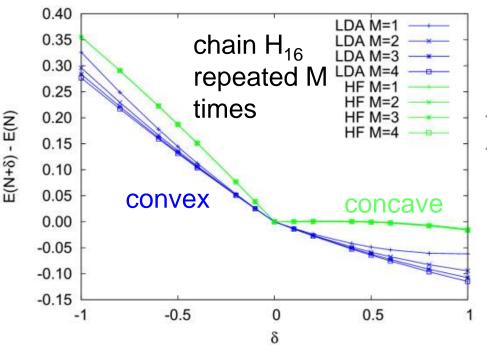
Hartree-Fock "overcorrects" the problem (correlation part is missing) Mori-Sánchez, Cohen, Yang, Phys. Rev. Lett. 100, 146401 (2008)

#### □ Hartree-Fock is self-interaction free, but...



Brice Arnaud, Universit´e de Rennes, France<sup>52</sup>

#### Hybrid functionals



Idea: combine HF with GGA to reduce the selfinteraction error:  $E[n] = \alpha E_X^{HF} + (1 - \alpha) E_X^{GGA} + E_C^{GGA}, 0 < \alpha < 1$ 

 $\alpha \neq 1$  because a non-local expression for correlation functional would otherwise be needed, but we don't know it, therefore - a balance

#### How to choose $\alpha$ ?

Mori-Sánchez, Cohen, Yang, Phys. Rev. Lett. 100, 146401 (2008)

**Hybrid functionals**  $E = \alpha E_X^{HF} + (1 - \alpha) E_X^{LDA/GGA} + E_C^{LDA/GGA}$ 

The mixing parameter  $\alpha$  depends on the choice of (semi)local exchange/correlation

 $E^{PBE0} = 0.25E_X^{HF}(\{\psi^{KS}\}) + 0.75E_X^{PBE} + E_C^{PBE}$  (choice of  $\alpha$  is based on perturbation theory (MP4))

Perdew, Ernzerhof, and Burke, J. Chem. Phys. 105, 9982 (1996)

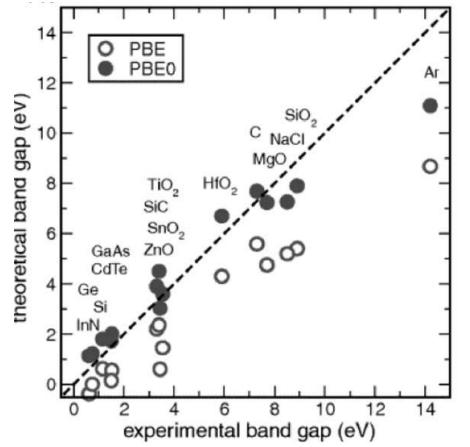
There can be other parameters

 $E^{HSE} = 0.25E_X^{HF,SR}(\omega) + 0.75E_X^{PBE,SR}(\omega) + E_X^{PBE,LR}(\omega) + E_C^{PBE}$  $\frac{1}{r} = SR_\omega(r) + LR_\omega(r) = \frac{\operatorname{erfc}(\omega r)}{r} + \frac{1 - \operatorname{erfc}(\omega r)}{r}$ 

J. Heyd, G. E. Scuseria, and M. Ernzerhof, J. Chem. Phys. **118**, 8207 (2003)

#### Hybrid functionals

 $E^{PBE0} = 0.25 E_X^{HF} (\{\psi^{KS}\}) + 0.75 E_X^{PBE} + E_C^{PBE}$ 



From: "Advanced Calculations for Defects in Materials: Electronic Structure Methods", Alkauskas, Deák, Neugebauer, Pasquarello, Van de Walle (eds.), Willey-VCH (2011)

#### Hybrid functionals

"An ideal hybrid would be sophisticated enough to optimize n for each system and property..."

Perdew, Ernzerhof, and BurkeJ. Chem. Phys. 105, 9982 (1996)

How can we do this?

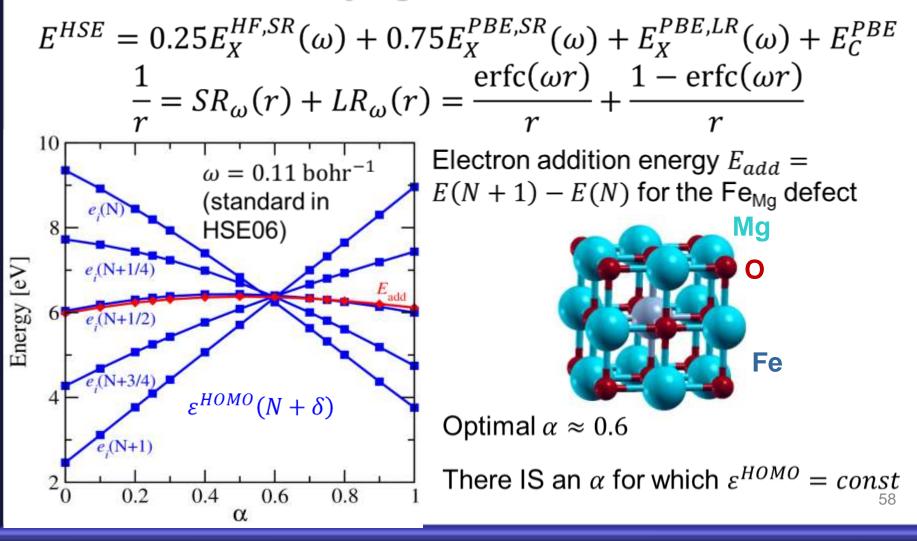
Example: Fe<sub>Mg</sub> defect in MgO

#### $\square$ Is $\alpha = 0.25$ always good?

$$E^{HSE} = 0.25E_X^{HF,SR}(\omega) + 0.75E_X^{PBE,SR}(\omega) + E_X^{PBE,LR}(\omega) + E_C^{PBE}$$
$$\frac{1}{r} = SR_{\omega}(r) + LR_{\omega}(r) = \frac{\operatorname{erfc}(\omega r)}{r} + \frac{1 - \operatorname{erfc}(\omega r)}{r}$$

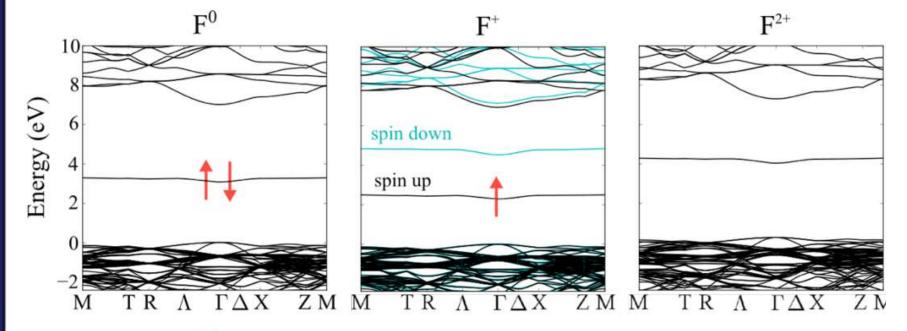
Example: Fe<sub>Ma</sub> defect in MgO

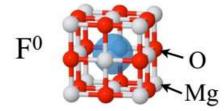
#### **I** Is $\alpha = 0.25$ always good?



Example: O vacancy in MgO

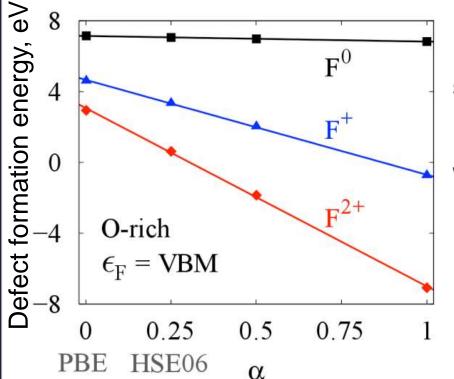
 $E^{HSE} = 0.25 E_X^{HF,SR}(\omega) + 0.75 E_X^{PBE,SR}(\omega) + E_X^{PBE,LR}(\omega) + E_C^{PBE}$ 





Example: O vacancy in MgO

 $E^{HSE} = 0.25 E_X^{HF,SR}(\omega) + 0.75 E_X^{PBE,SR}(\omega) + E_X^{PBE,LR}(\omega) + E_C^{PBE}$ 



HSE formation energies for varying  $\alpha$ : strong dependence for F<sup>+</sup> and F<sup>2+</sup>!

Which  $\alpha$  to use?

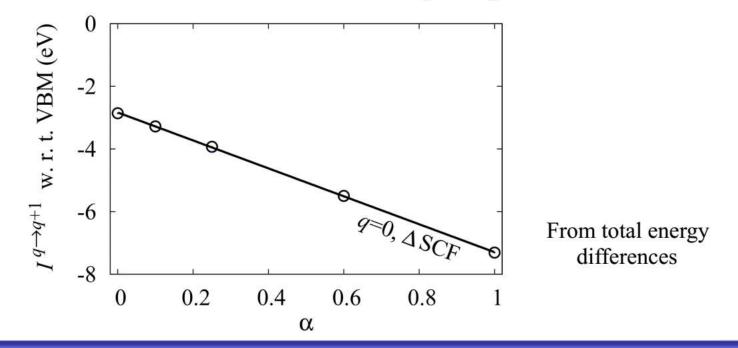
Example: O vacancy in MgO

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Request:

Ionization energies with opt-HSE and with  $G_0W_0$  opt-HSE should agree

calculated using an Mg<sub>6</sub>O<sub>9</sub> embedded cluster

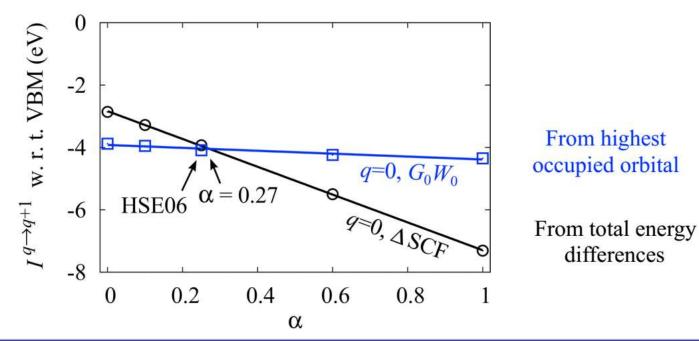


Example: O vacancy in MgO

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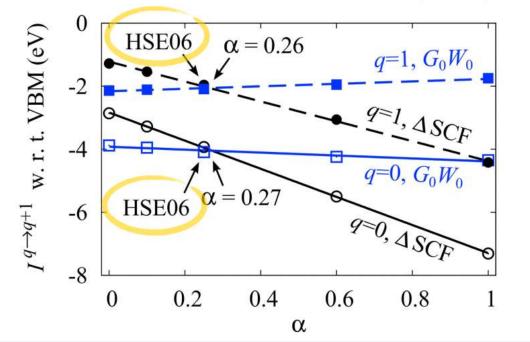
calculated using an Mg<sub>6</sub>O<sub>9</sub> embedded cluster

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Example: O vacancy in MgO

$$E^{HSE} = 0.25E_X^{HF,SR}(\omega) + 0.75E_X^{PBE,SR}(\omega) + E_X^{PBE,LR}(\omega) + E_C^{PBE}$$
  
Request:

Ionization energies with opt-HSE and with  $G_0W_0$  opt-HSE should agree



calculated using an Mg<sub>6</sub>O<sub>9</sub> embedded cluster

From highest occupied orbital

From total energy differences

Gradient-corrected density functionals

$$E_{xc}^{GGA} = \int d\mathbf{r} \ f[n(\mathbf{r}), \nabla n(\mathbf{r})]$$

#### Meta- GGA's

$$E_{xc}^{meta-GGA} = \int d\mathbf{r} \ g[n(\mathbf{r}), \nabla n(\mathbf{r}), \tau(r)]$$

### Orbital-dependent functionals

E.g., exact exchange

$$E_x^{EX} = -\frac{1}{2} \sum_{i,j}^{\text{occ}} \int d\mathbf{r} \ d\mathbf{r}' \frac{u_i^*(\mathbf{r}) u_j^*(\mathbf{r}') u_j(\mathbf{r}) u_i(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}$$

#### Jacob's ladder

John Perdew

#### HEMICAL ACCURACE 2 CHEMICAL ACCURAC RPA+ ... UNOCCUPIED ORBITALS HYPER-GGA 8 x META-GGA T GGA Vn LSDA HARTREE WORLD n HARTREE WORLD

#### from Kieron Burke

# The End ...